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# **Dielectric Laser Acceleration - Experiments**

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CAS Sesimbra, March 2019

#### Proposal for an Electron Accelerator Using an Optical Maser

#### Koichi Shimoda

January 1962 / Vol. 1, No. 1 / APPLIED OPTICS 33







## An old idea ... II

#### **TN-5** )()3

**Electron Acceleration** by Light Waves

October 3, 1962

A. Lohmann\*

Department 522 Photo-Optics Technology

**GPD** Development Laboratory San Jose



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## An old idea ... III

NUCLEAR INSTRUMENTS AND METHODS 62 (1968) 306-310; © NORTH-HOLLAND PUBLISHING CO.

#### LASER LINAC WITH GRATING

#### Y. TAKEDA and I. MATSUI

Central Research Laboratory, Hitachi Ltd., Kokubunji, Tokyo, Japan

Received 13 February 1968



Fig. 1. Schematic diagram of "laser linac with grating".

Electron Path

Fig. 2. Configuration of electric-field near grating surface.

Exp. demonstration with mm radiation (keV/m): Mizuno et al., Nature Nature 328, 45 (1987).

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# Proposed dielectric structures

Yoder

2005

Rosenzweig,







... and variants

Plettner, Lu, Byer, 2006

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- Goal: generate a mode that allows momentum transfer from laser field to electrons
- Use first order effect (efficient!)
- Second order effects (ponderomotive) too inefficient

For a review and an extensive list of references, see: R. J. England et al., "Dielectric laser accelerators", Rev. Mod. Phys. 86, 1337 (2014)



#### Proof-of-concept experiments

# 30 keV electron beam of an electron microscope column

60 MeV electron beam at SLAC's NLCTA





Single-sided silica structure 3<sup>rd</sup> spatial harmonic 25 MeV/m

J. Breuer, P. Hommelhoff, PRL 111, 134803 (2013)



Dual-sided silica structure 1<sup>st</sup> spatial harmonic > 250 MeV/m !

E. Peralta, Soong, K., England, R., Colby, E., Wu, Z., Montazeri, B., McGuinness, C., McNeur, J., Leedle, K., Walz, D., Sozer, E., Cowan, B., Schwartz, B., Travish, G., Byer, R. L., Nature 503, 91 (2013)





## Proof-of-concept experiments





J. Breuer, P. Hommelhoff, PRL 111, 134803 (2013)

E. Peralta, Soong, K., England, R., Colby, E., Wu, Z., Montazeri, B., McGuinness, C., McNeur, J., Leedle, K., Walz, D., Sozer, E., Cowan, B., Schwartz, B., Travish, G., Byer, R. L., Nature 503, 91 (2013)





# Accelerator on a chip











## ACHIP: Accelerator on a Chip International Program



(Only names of TG leaders given here. Many more involved in each group.)





# Grating structure

- Grating period: 620nm
- Grating depth: 450nm
- Challenge: get close enough (<200nm) to the grating surface without clipping the beam
  - → put grating on 20µm high mesa structure

electron beam focus



Silicon structures made by K. Leedle, H. Deng (Harris & Byer groups, Stanford)



## Demonstration of 2-stage acceleration



#### Image of laser intensity profiles on the grating

Energy gain can be doubled or suppressed depending on the relative phase of the 2 spots



Relative phase of laser spots is controlled with sub-cycle precision via a delay stage in one arm of an interferometer





## Demonstration of 2-stage acceleration



Count rates of accelerated electrons with energy gain >30 eV

J. McNeur, M. Kozak, N. Schoenenberger, K. J. Leedle, H. Deng, A. Ceballos, H. Hoogland, A. Ruehl, I. Hartl, O. Solgaard, J. S. Harris, R. L. Byer, P. Hommelhoff, Optica, 5, 687 (2018)

- Energy gain twice as large
- Linear scaling of energy





# Deflection – Origin of transversal forces

From theory lecture:

$$\vec{F} = q(\vec{E} + \vec{v} \times \vec{B}) = q \begin{pmatrix} icB_y/(\tilde{\beta}\tilde{\gamma}) + \tan\phi E_y \\ 0 \\ -cB_y(1 - \tilde{\beta}^2)/\tilde{\beta} + i\tan\phi E_y/\tilde{\gamma} \end{pmatrix}$$

In reference frame of particle

$$\vec{F} = q \begin{pmatrix} icB_y/(\tilde{\beta}\tilde{\gamma}) + \tan\phi E_y \\ -icB_y \tan\phi/(\tilde{\beta}\tilde{\gamma}) - \tan\phi \sin\phi E_y \\ -cB_y (1 - \tilde{\beta}^2)/\tilde{\beta} + i\tan\phi E_y/\tilde{\gamma} \end{pmatrix}$$

Particle can experience deflecting force in y





## Demonstration of 2-stage deflection



M. Kozak, J. McNeur, K. J. Leedle, N. Schoenenberger, A. Ruehl, I. Hartl, J. S. Harris, R. L. Byer, P. Hommelhoff, Nature Comm. 8, 14342 (2017)



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# Optical focusing of an electron beam



Move sample across focused electron beam (in x-direction)

• At each *x*-pos.: measure centroid of deflected (&accelerated) electron beam



J. McNeur, M. Kozak, N. Schoenenberger, K. J. Leedle, H. Deng, A. Ceballos, H. Hoogland, A. Ruehl, I. Hartl, O.

Solgaard, J. S. Harris, R.

L. Byer, P. Hommelhoff, Optica, 5, 687 (2018)



# Dual pillar structure driven from two sides



Dual pillar structure

- Easy to manufacture, in particular from silicon
- Large gradient: 370 MeV/m (with 100 keV electrons) demonstrated

Dual pillar structrues:

K. J. Leedle, A. Ceballos, H. Deng, O. Solgaard, R. F. Pease, R. L. Byer, and J. S. Harris, Opt. Lett. 40, 4344 (2015)







#### Acceleration and deflection controlled via optical phase



Opt. Lett. 43, 2181 (2018)



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Setup







#### New DLA structures: add distributed Bragg reflector

Dual pillar acceleration structures joint with **Bragg mirror** 







# Symmetric illumination via Bragg mirror





Incident field: 0.5 GV/m Pulse duration: 650 fs

#### P. Yousefi et al., MS in preparation





# Symmetric illumination via Bragg mirror



Incident field: 0.5 GV/m Pulse duration: 650 fs

P. Yousefi et al., MS in preparation

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# Sinusoidal structure





This structure shows very large excitation efficiency of the accelerating mode in simulations, achieving gradients of up to 700 MeV/m @  $\beta \approx 0.3$  (30 keV)

Fabricated structure shows gradient less than 100 MeV/m due to difficulties in the fabrication process since inside corners are too round! <





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# Length and power scaling

- I. Demonstration regime (small electron charge: not power-efficient, impedance matching unnecessary; based on simple scaling arguments; needs full scale simulations under way):
  - length given by laser peak field, focusing parameters and material damage threshold
  - 1 MeV final electron energy:

~1...10mm long DLA structure

- 1 kHz, 200 μJ, 0.2 W
- 100 kHz, 200 µJ, 20 W
- 1MHz, 200 µJ, 200 W
- 100 MeV final electron energy:
- ~ 0.1...1 m
- 20 mJ
- (10 GeV final electron energy):
  - 2 J

- *II.* **Operation regime** (bunch charge matching for power-efficient acceleration: impedance matching):
  - loaded gradient; typ. ½ of G<sub>0</sub>
  - spatial (transv.) and temporal (long.) matching of laser and electron pulse
  - Laser to electron beam transfer efficiency: percent level w/o cavity, 25% with intra-cavity.



Sieman, PR-STAB 7, 061303 (2004) Neil et al., PR-STAB 8, 031301 (2005)



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#### Vuckovic, Fan (Stanford): ACHIP photonics groups



Example device: dielectric 1550nm -1300 nm demultiplexer. Size: 2.8 x 2.8  $\mu$ m<sup>2</sup>



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#### On-chip laser power feeding: tree branch structure



T. W. Hughes, Si Tan, Z. Zhao, N. V. Sapra, K. J. Leedle, H. Deng, Yu Miao, D. S. Black, O. Solgaard, J. S. Harris, J. Vuckovic, R. L. Byer, S. Fan, Yun Jo Lee, Minghao Qi, Physical Review Applied 9, 054017 (2018)







# From pulsed energy to large field strengths



## Technology perspective: *photonics*

- Power and cost efficient laser technology
  - high average power
  - rugged turn-key fiber technology
- Optical field control available
- ✤ (Silicon) nanostructuring capabilities

Photonics technology!
World market for photonics: \$481 billion in 2012, expected \$620 billion in 2020 (Nat. Phot. 11, 1, 2016)

Similar story to radar klystrons (invented 1937) driving accelerator technology thereafter?







#### Even 3-d structures

McGuinness et al., J. Mod. Opt. 2009

Staude et al., Opt. Expr. 2012





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# Acceleration of 8 MeV electrons – SLAC



Reducing the pulse length of the laser from 1 ps to 100 fs leads to an increase in laser induced damage threshold

Resulting acceleration gradient increased to 700 MeV/m

Wootton et al., Opt. Lett. 41 12 (2016)





# PSI – Athos beam line of SwissFEL



Experimental chamber Is installed in the beamline.

Various sample holders and alignment features









# DESY – SINBAD R&D accelerator



SINBAD (currently under construction) will host relativistic DLA experiments with microbunched beams from mid 2019





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# Alternating phase focusing

Alternate between transverse focusing-longitudinal defocusing and transverse defocusing-longitudinal focusing **net focusing** 



First structure design that allows building the accelerator on a chip with 83 keV → >1 MeV: 56% transmission for 100pm, 93% for 25pm emittance

U. Niedermayer, T. Egenolf, O. Boine-Frankenheim, P. Hommelhoff, arXiv:1806.07287



# Phase-reset structure



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#### Various electron source approaches (Sub-) nanometer emittance requirement

PHYSICAL REVIEW SPECIAL TOPICS - ACCELERATORS AND BEAMS 15, 090702 (2012)

#### Nanometer emittance ultralow charge beams from rf photoinjectors

R. K. Li, K. G. Roberts, C. M. Scoby, H. To, and P. Musumeci Department of Physics and Astronomy, UCLA, Los Angeles, California 90095, USA



Diamond tip arrays (E. Simakov, Los Alamos)





Nanodiamondcoated tips (A. Tafel, FAU Erlangen)



Ultrahigh brightness source: LaB<sub>6</sub> nanowire (Li Ang, FAU Erlangen in collab. with Han Zhang, Tsukuba, Japan; Nature Nanotech. 11, 273 (2016) Flat photocathodes in ultralowcharge regime

Silicon beam tip (A. Ceballos, Solgaard group, Stanford)



Silicon tip line array (A. Ceballos, Solgaard group, Stanford)







#### Are laser-triggered electrons *spatially* coherent?





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# Fringes: DC vs. photo-emitted





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# LaB<sub>6</sub> nano wire sources



H. Zhang, et al., Nature Nanotechnology 11, 273 (2016).



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## Electron source characterization — LaB<sub>6</sub> nano wire emitter characteriztion

 $\rightarrow$ 

Electron coherence measurement  $\rightarrow$  Beam emittance



$$r_{\rm eff} = \frac{\lambda b}{\pi \xi_{\perp}}$$

Only upper limit of  $r_{\rm eff}$ 

 $\varepsilon_{\rm rms} = \frac{1}{\sqrt{2}} r_{\rm eff} \cdot \alpha_{\rm rms}$ 

Here,  $r_{\rm rms} = \frac{1}{\sqrt{2}} r_{\rm eff}$  , H. Lichte and M. Lehmann, 2008 Rep. Prog. Phys. 71 016102 \* M. Reiser, John Wiley & Sons, 2008.







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# Beam brightness measurement – LaB<sub>6</sub>





Laser triggered beam shows a good gaussian profile Beam divergence:

- Beam divergence (half opening angle) = 89 mrad (5.01°)
- RMS emittance: ≤ 0.1 nm rad
- Normalized rms emittance: ≤ 0.03 nm rad
- Normalized rms peak brightness: ≥ 1.13e+12 A/(cm<sup>2</sup> srad)\*

\* B<sub>norm.</sub> =  $I_{\text{peak}}/(\beta^2 \gamma^2 * \pi \alpha^2 \pi r_{\text{eff}}^2/2)$ 





# Beam brightness measurement – LaB<sub>6</sub>

MCP-Screen 10 200 200 200 200 200 200 200			<ul> <li>Beam divergence:</li> <li>Beam divergence (half opening angle) = 89 mrad (5.01°)</li> <li>RMS emittance: ≤ 0.1 nm rad</li> <li>Normalized rms emittance: ≤ 0.03 nm rad</li> </ul>						
	Parameter	LaB <sub>6</sub> NW	Flat DC (est.)	RF Gun	Diamond coated tips	W Tips	needed target		
いていたけためのである。	Normalized emittance (nm rad)	≤ 0.02	~40	5	TBD	0.1	<0.025		
	Peak Brightness (A/cm² srad)	≥ 1.1E+12	2.5E+8	5E+11	TBD	6E+12	>1E+13		
ため、ための		Notes: LaB <sub>6</sub> brightness @ 6fs W Tips is a combination from all the best measured values							



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# Limitations – damage threshold



Damage thresholds for different dielectrics





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Assume emittance limited beam:

$$r_{\rm m}'' + \frac{\gamma'' r_{\rm m}}{2\beta^2 \gamma} - \frac{\epsilon_{\rm n}^2}{\beta^2 \gamma^2 r_{\rm m}^3} = 0$$

transverse focusing with laser field:

$$\gamma^{\prime\prime} = \frac{2qE_{\perp}}{mc^2r_{\rm m}} = \frac{2G}{mc^2r_{\rm m}\gamma}$$

Demanding a stable beam radius yields:

$$\epsilon_{\rm n}^2 = \frac{2Gr_{\rm m}^3}{mc^2}$$

With G = 1 GeV/m and r = 100nm:  $\epsilon_n = 6 \, \mathrm{nm} \cdot \mathrm{rad}$  If perveance term (space charge, treat as perturbation) is 10% of the emittance term: **current limit** of

$$I_{\rm b} = 0.1 I_0 \frac{G\beta\gamma r_{\rm m}}{mc^2}$$





$\mathbf{P}$ (GV)	$E_{\rm kin} = 29  \rm keV,$ $r_{\rm m} = 50  \rm nm$			$\begin{aligned} E_{\rm kin} &= 957  \rm keV, \\ r_{\rm m} &= 300  \rm nm \end{aligned}$		
$E_{\rm p}\left(\frac{{\rm d} {\rm v}}{{\rm m}}\right)$	0.8	$\lambda (\mu \mathrm{m})$ 2	5	0.8	$\lambda (\mu { m m})$ 2	5
1	1.8 mA	4.4 mA	$11.2 \mathrm{mA}$	$0.28\mathrm{A}$	0.68 A	$1.72\mathrm{A}$
7	$12.6\mathrm{mA}$	$32 \mathrm{mA}$	80 mA	$1.9\mathrm{A}$	4.8 A	$12\mathrm{A}$
10	18 mA	$46\mathrm{mA}$	$114\mathrm{mA}$	$2.8\mathrm{A}$	6.8 A	$17.2\mathrm{A}$

Total charge (0.1 opt. period long pulse):

3 fC, scales with  $\lambda^2$ 

See also loaded acceleration efficiency:

R. H. Sieman, PR-STAB 7, 061303 (2004)

J. Breuer, J. McNeur, P. Hommelhoff, J. Phys. B. 47, 234004 (2014)





## ACHIP results so far

#### Proof-of-concept demonstration of DLA:

- ✓ 25 MeV/m at  $\beta$  = 0.3
- ✓ 250 MeV/m at  $\beta$  ~ 1

Cowan PR STAB 6, 101301 (2003) Plettner, Byer, et al., PRL 95, 134801 (2005) Na, Sieman, Byer, PR STAB 8, 031301 (2005) Zhang et al., PR STAB 8, 071302 (2005) Plettner et al., PR STAB 8, 121301 (2005) Plettner, Lu, Byer, PR STAB 9, 111301 (2006) Plettner, Byer, PR STAB 11, 030704 (2008) Plettner, Byer, NIMA 593, 63 (2008) Cowan PR STAB 11, 011301 (2008) McGuinness, Colby, Byer, J. Mod. Opt. 56, 2142 (2009) Plettner, Byer, Montazeri, J. Mod. Opt. 58, 1518 (2011) Soong, Byer, Opt. Lett., 37, 975 (2012) Peralta et al., Nature 503, 91 (2013) Wu et al., PR STAB 17, 081301 (2014) Bar-Lev, Scheuer, PR STAB 17, 121302 (2014) Aimidula et al., Phys. Plas. 21, 023110 (2014) Soong et al., Opt. Lett. 39, 4747 (2014) Leedle et al., Opt. Lett. 40, 4344 (2015) Leedle et al., Optica 2, 158 (2015) Wootton et al., Optl Lett. 41, 2696 (2016) Szczepkowicz, Appl. Opt. 55, 2634 (2016) Niedermayer et al., PR STAB (2017) Leedle et al., Opt. Lett. 43, 218 (2018) Hughes et al., Phys Rev. Appl. 9, 054017 (2018) Cesar et al. , arXiv:1801.01115 Cesar et al., arXiv:1804.00634 Cesar et al., arXiv:1707.02364

#### New structures

- phase-bases steering
- ✓ two-stage acceleration
- ✓ chirped structures
- ✓ optical focusing
- ✓ optical deflection
- beam position monitor
- ✓ (sub-) femtosecond bunching
- ✓ stable transport (theory)

#### Plettner et al., PR-STAB (2009) Breuer, Hommelhoff, PRL (2013)

Breuer et al., PR-STAB (2014) Breuer et al., J. Phys. B. (2014) McNeur et al., J. Phys. B. 49, 034006 (2016) Kozák et al., Opt. Lett. 41, 3435 (2016) McNeur et al., NIMA 829, 50 (2016) England et al., Rev. Mod. Phys. 2015 Kozák et al., Nature Comm. 8, 14342 (2017) Kozák et al., NIMA 865, 87 (2017) Prat et al., NIMA 865, 87 (2017) Prat et al., Opt. Expr. 25, 19195 (2017) McNeur et al., Optica t.b.p. (2018) Kozák et al. J. Appl. Phys. (2018) Niedermayer et al. Phys. Rev. Lett. (2018)



- ✓ 200.4 MeV/m with few-cycle NOPA-DFG (with  $\beta$  = 0.3 electrons!)
- ✓ **340 MeV/m** (with  $\beta$  = 0.7 electrons!)
- ✓ 850 MeV/m with 6 MeV electrons





# DLA research worldwide





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# Applications – Medical linacs







# Applications

• Intermediate term: medical irradiation source:



R. J. England et al., Rev. Mod. Phys. 86, 1337 (2014)

- Intraoperative electron beam radiation therapy (IOERT)
- Proximity radiation of tissue (minimally invasive "electron beam scalpel"?)
- Neuronal endplate treatment (Prof. Warren Grundfest, UCLA)
- New high dose rate radiation effects to be expected?





# Tabletop FEL?



Combination of DLA with laser driven undulators (possible with DLA technology) would yield a tabletop FEL capable of generating coherent x-ray radiation on the scale of an optical lab!





**Philip Dienstbier Timo Eckstein Christian Heide Jonas Heimerl** Martin Hundhausen **Johannes Illmer** Ang Li **Stefan Meier** Anna Mittelbach **Timo Paschen** Jürgen Ristein **Roy Shiloh Constanze Sturm** Alexander Tafel **Norbert Schönenberger Michael Seidling Philipp Weber Peyman Yousefi Robert Zimmermann** 



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NDATIO

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